**Vishay Semiconductors** 

RoHS COMPLIANT



# Hyperfast Rectifier, 5 A FRED Pt<sup>®</sup>



DPAK (TO-252AA)

	O 2, 4 ▲
) 1 1/C	3 O Anode

PRIMARY CHARACT	ERISTICS
I <sub>F(AV)</sub>	5 A
V <sub>R</sub>	600 V
V <sub>F</sub> at I <sub>F</sub>	1.55 V
t <sub>rr</sub> (typ.)	14 ns
T <sub>J</sub> max.	175 °C
Package	DPAK (TO-252AA)
Circuit configuration	Single

### **FEATURES**

- Hyperfast recovery time, extremely low Q<sub>rr</sub>
- 175 °C maximum operating junction temperature
- For PFC CCM operation
- · Low forward voltage drop
- Low leakage current
- HALOGEN • Meets MSL level 1, per J-STD-020, LF maximum FREE peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V						
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 144 °C	5							
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_J = 25 \ ^{\circ}C$	50	А						
Peak repetitive forward current	I <sub>FM</sub>	$T_{C} = 144 \ ^{\circ}C, f = 20 \ \text{kHz}, d = 50 \ \%$	10							
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)										
PARAMETER	ARAMETER SYMBOL TEST CONDITIONS				MAX.	UNITS				
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-					
Forward voltage	N	I <sub>F</sub> = 5 A	-	2.39	2.9	V				
	V <sub>F</sub>	I <sub>F</sub> = 5 A, T <sub>J</sub> = 150 °C	-	1.55	1.8					
Deverae leekerse eurrent		$V_{R} = V_{R}$ rated	-	-	20					
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	250	μA				
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	3.5	-	pF				
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH				

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 10$	00 A/µs, V <sub>R</sub> = 30 V	-	14	21			
	+	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50$	-	16	-	ns			
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	18	-	A nC		
		T <sub>J</sub> = 125 °C	$I_F = 5 A$	-	27	-			
Book receiver ( ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	3.0	-			
Peak recovery current		T <sub>J</sub> = 125 °C	dl <sub>F</sub> /dt = 200 A/µs V <sub>B</sub> = 390 V	-	3.9	-			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	26	-			
		T <sub>J</sub> = 125 °C		-	54	-			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C				
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	-	3	°C/W				
Approximate weight				0.3		g				
Approximate weight				0.01		oz.				
Marking device		Case style DPAK (TO-252AA)	5EWX06FN							

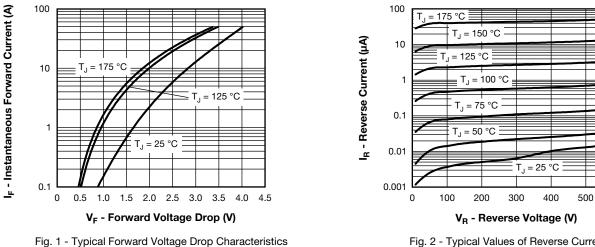


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

600



# VS-5EWX06FN-M3

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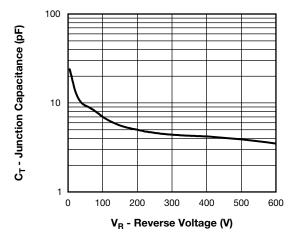


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

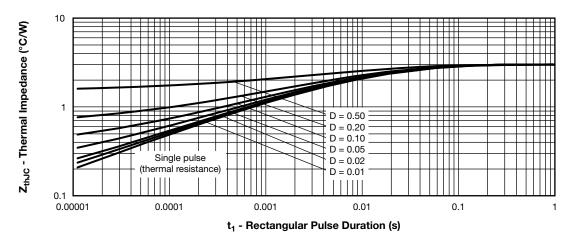
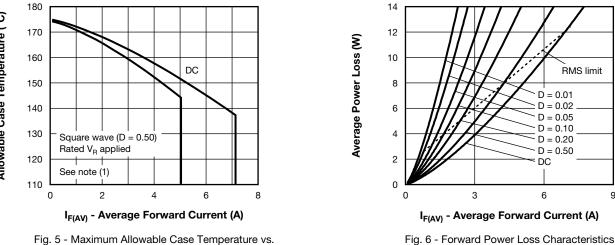


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



Average Forward Current

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RMS limit

9

D = 0.01 D = 0.02

D = 0.05 D = 0.10

<sup>–</sup> D = 0.20

DC

6

D = 0.50

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Allowable Case Temperature (°C)

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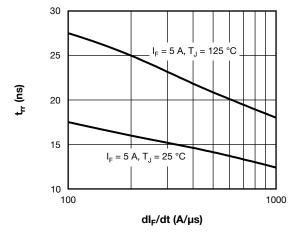


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;  $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 D)$ ;  $I_R at V_{R1} = rated V_R$

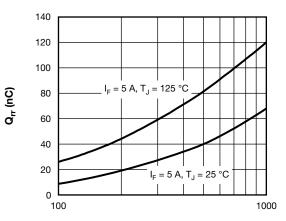




Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

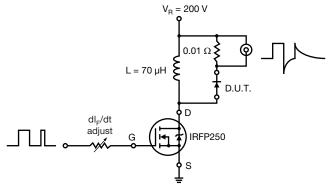


Fig. 9 - Reverse Recovery Parameter Test Circuit

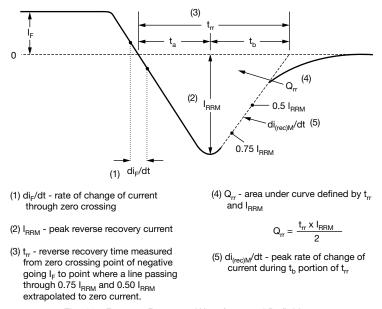


Fig. 10 - Reverse Recovery Waveform and Definitions

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### **Vishay Semiconductors**

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**ORDERING INFORMATION TABLE** 

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		1	1					1			
Device code	vs-	5	E	w	X	06	FN	TRL	-M3		
		<u> </u>	<u> </u>	<u> </u>							
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)		
	_	$\bigcirc$	Ŭ	Ŭ	Ŭ	$\cup$	$\cup$	Ŭ	$\cup$		
	1	- Visl	hay Serr	niconduc	ctors pro	oduct					
	2	- Cur	rent rati	ng (5 =	5 A)						
	3	- Circ	Circuit configuration:								
		E =	E = single diode								
	4	- Pac	Package identifier:								
		W =	= D-PAK	,							
	5	- X=	hyperfa	st recov	ery time	9					
			tage rati		-						
			= TO-25		,						
			one = tu								
					51						
			• TR = tape and reel								
			<ul> <li>TRL = tape and reel (left oriented)</li> </ul>								
	_	• TI	RR = tap	be and r	eel (righ	nt orient	ed)				
	9	- Env	vironmer	ntal digit	:						
				-							

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION							
VS-5EWX06FN-M3	75	Antistatic plastic tube							
VS-5EWX06FNTR-M3	2000	13" diameter reel							
VS-5EWX06FNTRL-M3	3000	13" diameter reel							
VS-5EWX06FNTRR-M3	3000	13" diameter reel							

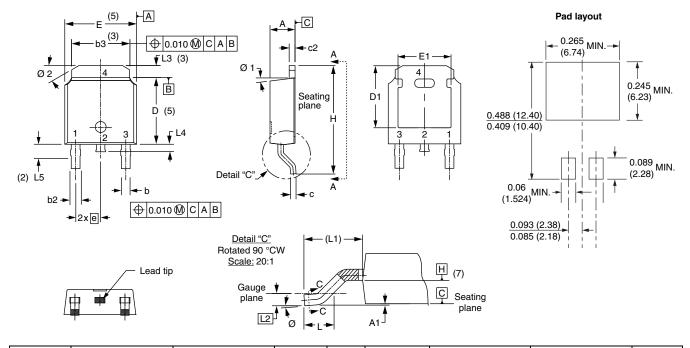
LINKS TO RELATED DOCUMENTS								
Dimensions	www.vishay.com/doc?95627							
Part marking information	www.vishay.com/doc?95176							
Packaging information	www.vishay.com/doc?95033							
SPICE model	www.vishay.com/doc?95215							





D-PAK (TO-252AA) "M"

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INC	INCHES		SYMBOL		MILLIN	IETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTED	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	) BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	BREF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(6)</sup> Dimension b1 and c1 applied to base metal only

<sup>(7)</sup> Datum A and B to be determined at datum plane H

<sup>(8)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-252AA



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